ABSOLUTE MAXIMUM RATINGS

(All voltages referenced to GND.)

+6V
0.3V to +6V
8V to 13V
Continuous
471mW
380.6mW

Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +5V \pm 5\%, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +5V$ and $T_A = +25^{\circ}C$.) (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIC	DNS	MIN	ТҮР	MAX	UNITS
DRIVER	•			•			•
		$R_{DIFF} = 100\Omega$, Figure 1		2.0		VCC	
Differential Driver Output	VOD	$R_{DIFF} = 54\Omega$, Figure 1		1.5			V
		No load				V _C C]
Change in Magnitude of Differential Output Voltage	ΔV _{OD}	$R_{DIFF} = 100\Omega \text{ or } 54\Omega$, Fig	ure 1 (Note 3)			0.2	V
Driver Common-Mode Output Voltage	Voc	$R_{DIFF} = 100\Omega \text{ or } 54\Omega$, Fig	ure 1		V _{CC} / 2	3	V
Change in Magnitude of Common-Mode Voltage	ΔV _{OC}	$R_{DIFF} = 100\Omega \text{ or } 54\Omega$, Fig	ure 1 (Note 3)			0.2	V
Input-High Voltage	VIH	DI, DE, RE		2.0			V
Input-Low Voltage	VIL	DI, DE, RE				0.8	V
Input Current	lin	DI, DE, RE				±1	μΑ
Driver Short-Circuit Output	IOSD	$0V \le V_{OUT} \le +12V$		+50		+250	mA
Current (Note 4)	IOSD	-7V <u><</u> V _{OUT} <u><</u> 0V		-250		-50	ША
Driver Short-Circuit Foldback	0005	$(V_{CC} - 1V) \leq V_{OUT} \leq +12V$	/	20			mA
Output Current Note 3)	IOSDF	-7V <u><</u> V _{OUT} <u><</u> 0V				-20	ШA
RECEIVER							
Input Current (A and B)	IA. B	$DE = GND, V_{CC} = GND$	$V_{IN} = +12V$			250	μA
input current (A and B)	IA, B	or +5V	$V_{IN} = -7V$	-200			μΑ
Receiver-Differential-Threshold Voltage	V _{TH}	$-7V \le V_{CM} \le +12V$		-200		-50	mV
Receiver Input Hysteresis	ΔV_{TH}	$V_A + V_B = 0V$			25		mV
Output-High Voltage	VOH	$I_{O} = -1.6 mA, V_{A} - V_{B} > V_{T}$	Ή	V _{CC} - 1.5			V

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +5V \pm 5\%, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } V_{CC} = +5V \text{ and } T_A = +25^{\circ}C.)$ (Notes 1, 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Output-Low Voltage	V _{OL}	I_{O} = 1mA, V_{A} - V_{B} < - V_{TH}			0.4	V
Tri-State Output Current at Receiver	I _{OZR}	$0V \le V_O \le V_{CC}$			±1	μA
Receiver Input Resistance	RIN	$-7V \leq V_{CM} \leq +12V$	48			kΩ
Receiver-Output Short-Circuit Current	IOSR	$0V \le V_{RO} \le V_{CC}$	±7		±95	mA
POWER SUPPLY		•				
Supply Voltage	V _{CC}		4.75		5.25	V
Supply Current	Icc	$DE = 1, \overline{RE} = 0, no load$			4.5	mA
Shutdown Supply Current	ISHDN	$DE = 0, \overline{RE} = 1$			10	μΑ
ESD PROTECTION						
ESD Protection (A, B)		Air Gap Discharge IEC61000-4-2 (MAX13485E)		±15		kV
		Human Body Model		±15		1
ESD Protection (All Other Pins)		Human Body Model		±2		kV

SWITCHING CHARACTERISTICS-MAX13485E

 $(V_{CC} = +5V \pm 5\%, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +5V$ and $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
DRIVER						
Driver Propagation Dolay	t DPLH	RDIFF = 54Ω , CI = 50pF, Figures 2 and 3	200		1000	20
Driver Propagation Delay	t DPHL	HDIFF = 5452, CL = 50pF, Figures 2 and 3	200		1000	ns
Driver-Differential Output Rise or	tHL	$R_{\text{DIFF}} = 54\Omega$, $C_{\text{I}} = 50$ pF, Figures 2 and 3	250		900	ns
Fall Time	tLH	10 [FF = 3432, CL = 30 [F, 11 guies 2 and 3	250		900	115
Driver-Differential Output Skew ItDPLH - tDPHLI	t DSKEW	R_{DIFF} = 54 Ω,C_{L} = 50pF, Figures 2 and 3			140	ns
Maximum Data Rate			500			kbps
Driver Enable to Output High	t _{DZH}	Figures 4 and 5			2500	ns
Driver Enable to Output Low	t _{DZL}	Figures 4 and 5			2500	ns
Driver Disable Time from High	t _{DHZ}	Figures 4 and 5			100	ns
Driver Disable Time from Low	t _{DLZ}	Figures 4 and 5			100	ns
Driver Enable from Shutdown to Output High	tDZH(SHDN)	Figures 4 and 5			5500	ns
Driver Enable from Shutdown to Output Low	tDZL(SHDN)	Figures 4 and 5			5500	ns
Time to Shutdown	t _{SHDN}		50	340	700	ns
RECEIVER						
Pageiver Propagation Dalay	t _{RPLH}			80		
Receiver Propagation Delay	t RPHL	$C_L = 15pF$, Figures 6 and 7			80	ns
Receiver Output Skew	t RSKEW	C _L = 15pF, Figure 7			13	ns
Maximum Data Rate			500			kbps

SWITCHING CHARACTERISTICS—MAX13485E (continued)

 $(V_{CC} = +5V \pm 5\%, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +5V$ and $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Receiver Enable to Output High	trzh	Figure 8			50	ns
Receiver Enable to Output Low	t _{RZL}	Figure 8			50	ns
Receiver Disable Time from High	trhz	Figure 8			50	ns
Receiver Disable Time from Low	t _{RLZ}	Figure 8			50	ns
Receiver Enable from Shutdown to Output High	^t RZH(SHDN)	Figure 8			2200	ns
Receiver Enable from Shutdown to Output Low	tRZL(SHDN)	Figure 8			2200	ns
Time to Shutdown	^t SHDN		50	340	700	ns

SWITCHING CHARACTERISTICS-MAX13486E

 $(V_{CC} = +5V \pm 5\%, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +5V$ and $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
DRIVER						
Driver Propagation Delay	t _{DPLH}	$R_{DIFF} = 54\Omega$, $C_{L} = 50pF$, Figures 2 and 3			50	
	t DPHL	DIFF = 5432, CL = 50PF, Figures 2 and 3			50	ns
Driver Differential Output Rise or	tHL	$R_{DIFF} = 54\Omega$, $C_{L} = 50pF$, Figures 2 and 3			15	ns
Fall Time	tLH	TDFF = S432, CL = S0PI, Tigules Z and S			15	115
Differential Driver Output Skew ItDPLH - tDPHLI	t DSKEW	R_{DIFF} = 54 Ω,C_{L} = 50pF, Figures 2 and 3			8	ns
Maximum Data Rate			16			Mbps
Driver Enable to Output High	t _{DZH}	Figures 4 and 5			50	ns
Driver Enable to Output Low	t _{DZL}	Figures 4 and 5			50	ns
Driver Disable Time from High	t _{DHZ}	Figures 4 and 5			50	ns
Driver Disable Time from Low	tDLZ	Figures 4 and 5			50	ns
Driver Enable from Shutdown to Output High	^t DZH(SHDN)	Figures 4 and 5			2200	ns
Driver Enable from Shutdown to Output Low	^t DZL(SHDN)	Figures 4 and 5			2200	ns
Time to Shutdown	^t SHDN		50	340	700	ns
RECEIVER		-	-			
Receiver Propagation Delay	t _{RPLH}	C: 15pE Figures 6 and 7		80	ns	
Receiver Propagation Delay	t _{RPHL}	$C_L = 15pF$, Figures 6 and 7			80	115
Receiver Output Skew	t RSKEW	$C_L = 15 pF$, Figure 7			13	ns
Maximum Data Rate			16			Mbps

M/IXI/N

SWITCHING CHARACTERISTICS—MAX13486E (continued)

 $(V_{CC} = +5V \pm 5\%, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +5V$ and $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Receiver Enable to Output High	t _{RZH}	Figure 8			50	ns
Receiver Enable to Output Low	t _{RZL}	Figure 8			50	ns
Receiver Disable Time from High	t _{RHZ}	Figure 8			50	ns
Receiver Disable Time from Low	t _{RLZ}	Figure 8			50	ns
Receiver Enable from Shutdown to Output High	^t RZH(SHDN)	Figure 8			2200	ns
Receiver Enable from Shutdown to Output Low	tRZL(SHDN)	Figure 8			2200	ns
Time to Shutdown	t _{SHDN}		50	340	700	ns

Note 1: µDFN devices production tested at +25°C. Overtemperature limits are generated by design.

Note 2: All currents into the device are positive. All currents out of the device are negative. All voltages referred to device ground, unless otherwise noted.

Note 3: ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} when the DI input changes states.

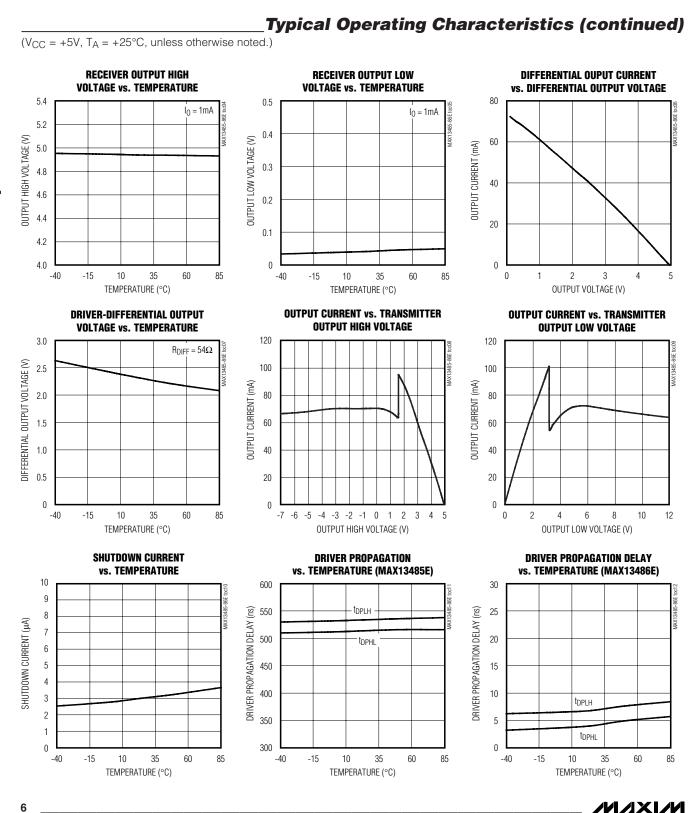
 $(V_{CC} = +5V, T_A = +25^{\circ}C, unless otherwise noted.)$

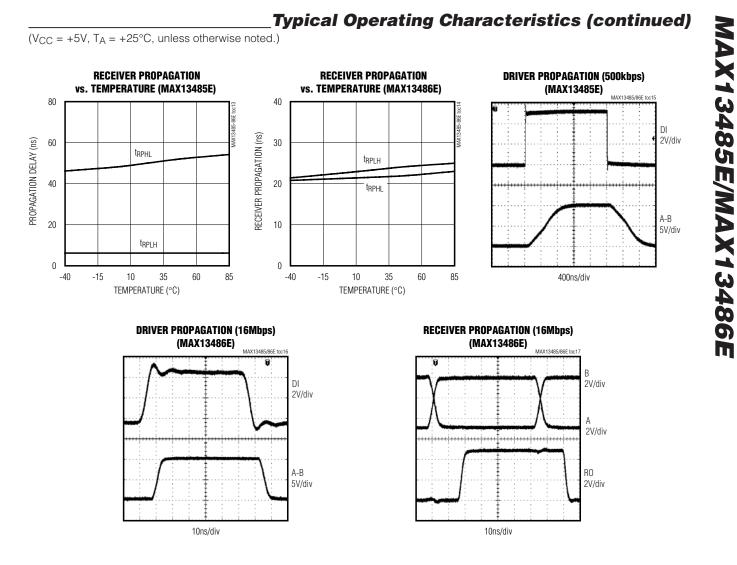
Note 4: The short-circuit output current applied to peak current just prior to foldback current limiting. The short-circuit foldback output current applies during current limiting to allow a recovery from bus contention.

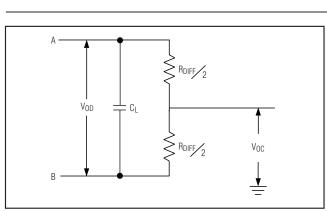
OUTPUT CURRENT vs. RECEIVER OUTPUT CURRENT vs. RECEIVER OUTPUT HIGH VOLTAGE OUTPUT LOW VOLTAGE SUPPLY CURRENT vs. TEMPERATURE 35 60 4.0 NO LOAD 50 28 3.8 OUTPUT CURRENT (mA) **DUTPUT CURRENT (mA)** SUPPLY CURRENT (mA) 40 21 3.6 30 14 3.4 20 7 3.2 10 0 0 3.0 0 1 2 3 4 5 0 1 2 3 4 -40 -15 10 35 60 85 OUTPUT HIGH VOLTAGE (V) OUTPUT LOW VOLTAGE (V) TEMPERATURE (°C)

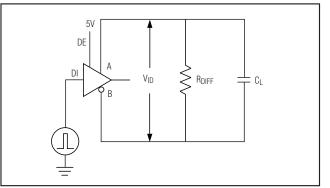
Typical Operating Characteristics











Test Circuits and Waveforms

Figure 1. Driver DC Test Load

Figure 2. Driver Timing Test Circuit

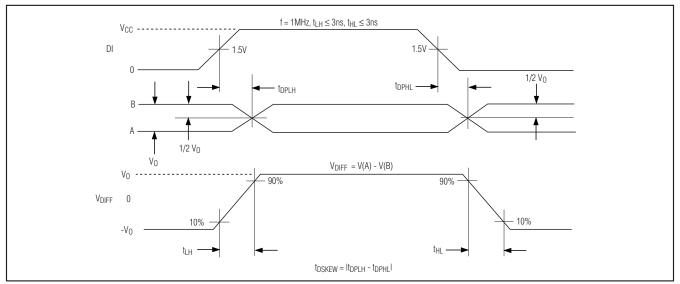
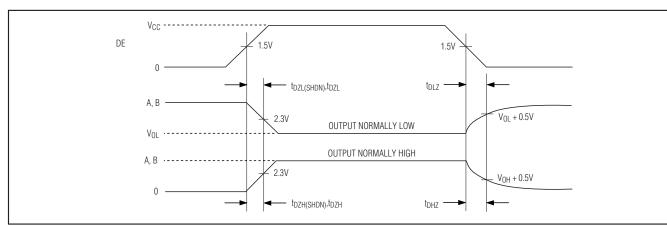


Figure 3. Driver Propagation Delays



_Test Circuits and Waveforms (continued)

Figure 4. Driver Enable and Disable Times

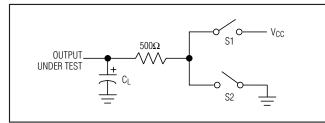


Figure 5. Driver-Enable and -Disable-Timing Test Load

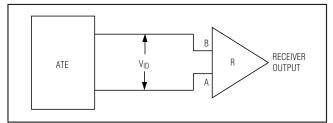
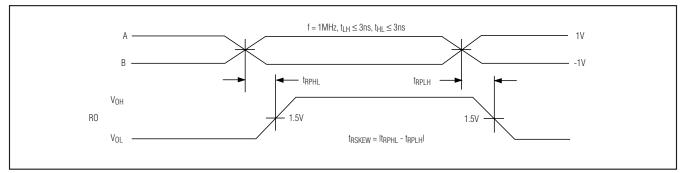


Figure 6. Receiver Propagation Delay Test Circuit







Pin Description

PIN	NAME	FUNCTION
1	RO	Receiver Output
2	RE	Receiver Output Enable. Drive $\overline{\text{RE}}$ low to enable RO. RO is high impedance when $\overline{\text{RE}}$ is high. Drive $\overline{\text{RE}}$ high and DE low to enter low-power shutdown mode. $\overline{\text{RE}}$ is a hot-swap input (see the <i>Hot-Swap Capability</i> section for more details).
3	DE	Driver Output Enable. Drive DE high to enable the driver outputs. These outputs are high-impedance when DE is low. Drive \overline{RE} high and DE low to enter low-power shutdown mode. DE is a hot-swap input (see the <i>Hot-Swap Capability</i> section for more details).
4	DI	Driver Input. Drive DI low to force noninverting output low and inverting output high. Drive DI high to force noninverting output high and inverting output low (see the <i>Function Tables</i>).
5	GND	Ground
6	А	Noninverting Receiver Input and Noninverting Driver Output
7	В	Inverting Receiver Input and Inverting Driver Output
8	Vcc	Positive Supply, $V_{CC} = +5V \pm 5\%$. Bypass V_{CC} to GND with a 0.1µF capacitor.

Function Tables

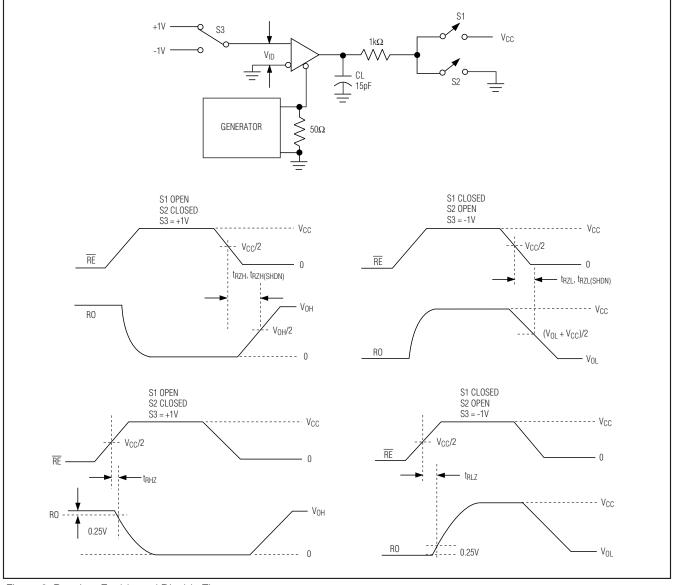
	TRANSMITTING							
	INPUT		OUTPUT					
RE	DE	DI	В	А				
Х	1	1	0	1				
Х	1	0	1	0				
0	0	Х	HIGH IMPEDANCE	HIGH IMPEDANCE				
1	0	Х	SHUTI	DOWN				

RECEIVING						
	INP	TUT	OUTPUT			
RE	DE	A-B	RO			
0	Х	<u>></u> -50mV	1			
0	Х	<u><</u> -200mV	0			
0	Х	OPEN/SHORT	1			
1	1	Х	HIGH IMPEDANCE			
1	0	Х	SHUTDOWN			

X = Don't care, shutdown mode, driver, and receiver outputs are in high impedance.

///// 10





_Test Circuits and Waveforms (continued)

Figure 8. Receiver Enable and Disable Times

Detailed Description

The MAX13485E/MAX13486E half-duplex, high-speed transceivers for RS-485/RS-422 communication contain one driver and one receiver. These devices feature failsafe circuitry that guarantees a logic-high receiver output when receiver inputs are open or shorted, or when they are connected to a terminated transmission line with all drivers disabled (see the Fail-Safe section). The MAX13485E/MAX13486E also feature a hot-swap capability allowing line insertion without erroneous data transfer (see the Hot-Swap Capability section). The MAX13485E features reduced slew-rate drivers that minimize EMI and reduce reflections caused by improperly terminated cables, allowing error-free transmission up to 500kbps. The MAX13486E driver slew rate is not limited, making transmit speeds up to 16Mbps possible.

Fail-Safe

The MAX13485E/MAX13486E guarantee a logic-high receiver output when the receiver inputs are shorted or open, or when they are connected to a terminated transmission line with all drivers disabled. This is done by setting the receiver input threshold between -50mV and -200mV. If the differential receiver input voltage (A - B) is greater than or equal to -50mV, RO is logic-high. If (A - B) is less than or equal to -200mV, RO is logic-low. In the case of a terminated bus with all transmitters disabled, the receiver's differential input voltage is pulled to 0V by the termination. With the receiver thresholds of the MAX13485E/MAX13486E, this results is a logic-high with a 50mV minimum noise margin. Unlike previous fail-safe devices, the -50mV to -200mV threshold complies with the ±200mV EIA/TIA-485 standard.

Hot-Swap Capability

Hot-Swap Inputs

When circuit boards are inserted into a hot or powered backplane, differential disturbances to the data bus can lead to data errors. Upon initial circuit-board insertion, the data communication processor undergoes its own power-up sequence. During this period, the processor's logic-output drivers are high impedance and are unable to drive the DE and \overline{RE} inputs of these devices to a defined logic level. Leakage currents up to $\pm 10\mu A$ from the high impedance state of the processor's logic drivers could cause standard CMOS enable inputs of a transceiver to drift to an incorrect logic level. Additionally, parasitic circuit-board capacitance could cause coupling of V_{CC} or GND to the enable inputs. Without the hot-swap capability, these factors could improperly enable the transceiver's driver or receiver.

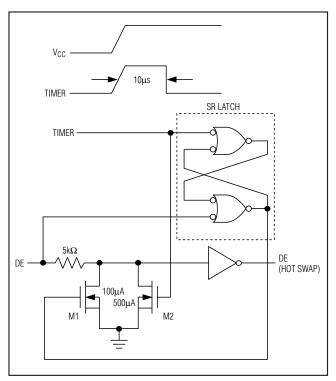


Figure 9. Simplified Structure of the Driver Enable Pin (DE)

When V_{CC} rises, an internal pulldown circuit holds DE low and \overline{RE} high. After the initial power-up sequence, the pulldown circuit becomes transparent, resetting the hot-swap tolerable input.

Hot-Swap Input Circuitry

The enable inputs feature hot-swap capability. At the input there are two nMOS devices, M1 and M2 (Figure 9). When V_{CC} ramps from zero, an internal 7µs timer turns on M2 and sets the SR latch, which also turns on M1. Transistors M2, a 1.5mA current sink, and M1, a 500 μ A current sink, pull DE to GND through a 5k Ω resistor. M2 is designed to pull DE to the disabled state against an external parasitic capacitance up to 100pF that can drive DE high. After 7µs, the timer deactivates M2 while M1 remains on, holding DE low against tristate leakages that can drive DE high. M1 remains on until an external source overcomes the required input current. At this time, the SR latch resets and M1 turns off. When M1 turns off, DE reverts to a standard highimpedance CMOS input. Whenever V_{CC} drops below 1V, the hot-swap input is reset.

For $\overline{\text{RE}}$ there is a complementary circuit employing two pMOS devices pulling $\overline{\text{RE}}$ to $V_{CC}.$



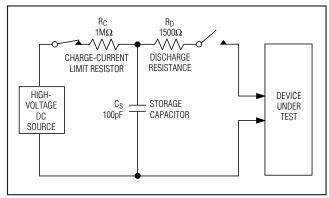


Figure 10a. Human Body ESD Test Model

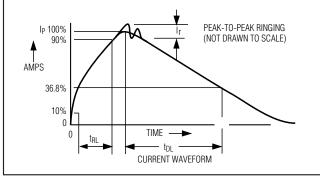


Figure 10b. Human Body Current Waveform

<u>+</u>15V ESD Protection

As with all Maxim devices, ESD-protection structures are incorporated on all pins to protect against electrostatic discharges encountered during handling and assembly. The driver outputs and receiver inputs of the MAX13485E/MAX13486E have extra protection against static electricity. Maxim's engineers have developed state-of-the-art structures to protect these pins against ESD of ± 15 kV without damage. The ESD structures withstand high ESD in all states: normal operation, shutdown, and powered down. After an ESD event, the MAX13485E/MAX13486E keep working without latchup or damage.

ESD protection can be tested in various ways. The transmitter outputs and receiver inputs of the MAX13485E/ MAX13486E are characterized for protection to the following limits:

- ±15kV using the Human Body Model
- ±15kV using the Air Gap Discharge Method specified in IEC 61000-4-2 (MAX13485E only)

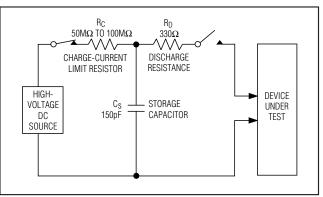


Figure 10c. IEC 61000-4-2 ESD Test Model

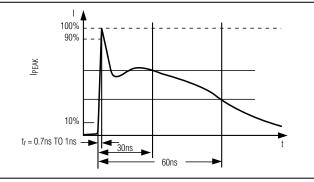


Figure 10d. IEC 61000-4-2 ESD Generator Current Waveform

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

Human Body Model

Figure 10a shows the Human Body Model, and Figure 10b shows the current waveform it generates when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the test device through a $1.5k\Omega$ resistor.

IEC 61000-4-2

The IEC 61000-4-2 standard covers ESD testing and performance of finished equipment. However, it does not specifically refer to integrated circuits. The MAX13485E/MAX13486E help equipment designs to meet IEC 61000-4-2, without the need for additional ESD-protection components.

The major difference between tests done using the Human Body Model and IEC 61000-4-2 is higher peak current in IEC 61000-4-2 because series resistance is lower in the IEC 61000-4-2 model. Hence, the ESD



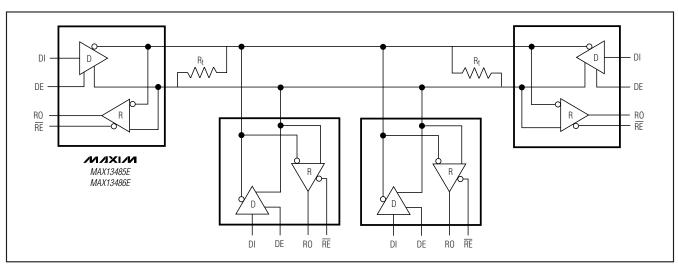


Figure 11. Typical Half-Duplex RS-485 Network

withstand voltage measured to IEC 61000-4-2 is generally lower than that measured using the Human Body Model. Figure 10c shows the IEC 61000-4-2 model, and Figure 10d shows the current waveform for the IEC 61000-4-2 ESD Contact Discharge test.

Machine Model

The machine model for ESD tests all pins using a 200pF storage capacitor and zero discharge resistance.

The objective is to emulate the stress caused when I/O pins are contacted by handling equipment during test and assembly. Of course, all pins require this protection, not just RS-485 inputs and outputs.

The air-gap test involves approaching the device with a charged probe. The contact-discharge method connects the probe to the device before the probe is energized.

Applications Information

128 Transceivers on the Bus

The standard RS-485 receiver input impedance is $12k\Omega$ (1-unit load), and the standard driver can drive up to 32-unit loads. The MAX13485E/MAX13486E have a 1/4-unit load receiver input impedance (48k Ω), allowing up to 128 transceivers to be connected in parallel on one communication line. Any combination of these devices, as well as other RS-485 transceivers with a total of 32-unit loads or fewer, can be connected to the line.

Reduced EMI and Reflections

The MAX13485E features reduced slew-rate drivers that minimize EMI and reduce reflections caused by improperly terminated cables, allowing error-free data transmission up to 500kbps.

Low-Power Shutdown Mode

Low-power shutdown mode is initiated by bringing both $\overline{\text{RE}}$ high and DE low. In shutdown, the devices draw a maximum of 10µA of supply current.

RE and DE can be driven simultaneously. The devices are guaranteed not to enter shutdown if RE is high and DE is low for less than 50ns. If the inputs are in this state for at least 700ns, the devices are guaranteed to enter shutdown.

Enable times t_{ZH} and t_{ZL} (see the *Switching Characteristics*) assume the devices were not in a low-power shutdown state. Enable times $t_{ZH(SHDN)}$ and $t_{ZL(SHDN)}$ assume the devices were in shutdown state. It takes drivers and receivers longer to become enabled from low-power shutdown mode ($t_{ZH(SHDN)}$, $t_{ZL(SHDN)}$) than from driver-/receiver-disable mode (t_{ZH} , t_{ZL}).

Line Length

The RS-485/RS-422 standard covers line lengths up to 4000ft.

Typical Applications

The MAX13485E/MAX13486E transceivers are designed for half-duplex, bidirectional data communications on multipoint bus transmission lines. Figure 11 shows typical network applications circuits. To minimize reflections, terminate the line at both ends in its characteristic impedance, and keep stub lengths off the main line as short as possible. The slew-rate-limited MAX13485E is more tolerant of imperfect termination.

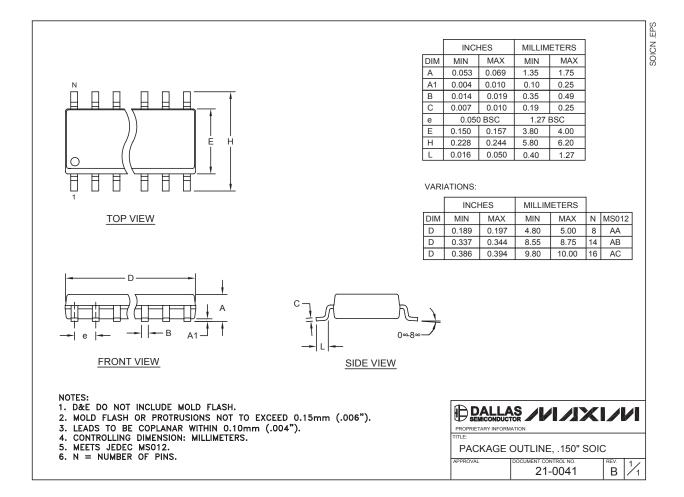
Chip Information

PROCESS: BICMOS



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

10L UDFN.EPS – A – D XXXX 6, 8, SOLDEF XXXX ASK OVERAGE XXXX F L 11 PIN 1 SAMPLE (N/2 -1) x e) BOTTOM VIEW TOP VIEW SIDE VIEW DETAIL A - b |-L. Α e - ei SECTION A-A А1 Ц ODD TERMINAL EVEN TERMINAL SIDE VIEW PACKAGE OUTLINE, 6, 8, 10L uDFN, 2x2x0.80 m A 1/2 21-0164 -DRAWING NOT TO SCALE COMMON DIMENSIONS SYMBOL MIN. NOM. MAX. A 0.70 0.75 0.80 A 0.15 0.20 0.25 0.020 0.035 A2 0.025 1.95 2.00 2.05 F 1.95 2.00 2.05 L 0.30 0.40 0.50 0.10 RE PACKAGE VARIATIONS PKG. CODE Ν (N/2 -1) x e b е 0.65 BSC 0.30±0.05 1.30 REF. L622-1 6 L822-1 8 0.50 BSC 0.25±0.05 1.50 REF. L1022-1 10 0.40 BSC 0.20±0.03 1.60 REF NOTES: 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES. 2. COPLANARITY SHALL NOT EXCEED 0.08mm. 3. WARPAGE SHALL NOT EXCEED 0.10mm. 4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS DESCRIMENTION OF MACHINER OF MACHINER OF MACHINER SPECIAL CHARACTERISTIC(S). "N" IS THE TOTAL NUMBER OF LEADS. NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY. MARKING IS FOR PACKAGE DRIENTATION REFERENCE ONLY. BALLAS ////XI// Å PACKAGE OUTLINE 6, 8, 10L uDFN A 2/2 DRAWING NOT TO SCALE 21-0164

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